A double-emitter silicon differential strain sensitive transistor with an accelerating field in its base
Babichev, G.G.; Kozlovskii, S.I.; Romanov, V.A.; Sharan, N.N. BEC'98: the 6th Biennial Conference on Electronics and Microsystems
Technology, October 7-9, 1998, Tallinn, Estonia: proceedings 1998 / p. 263-264: ill